NSN 5961-01-016-2781

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-016-2781 **Inclosure Material:** Metal **Overall Length:** 0.330 inches **Terminal Length:** Between 0.360 inches and 0.440 inches **Overall Diameter:** 0.650 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-8 **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.136 inches and 0.146 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 nonrepetitive peak reverse voltage and 100.0 nonrepetitive peak off-state voltage **Current Rating Per Characteristic:** 33.00 amperes forward current, average **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0